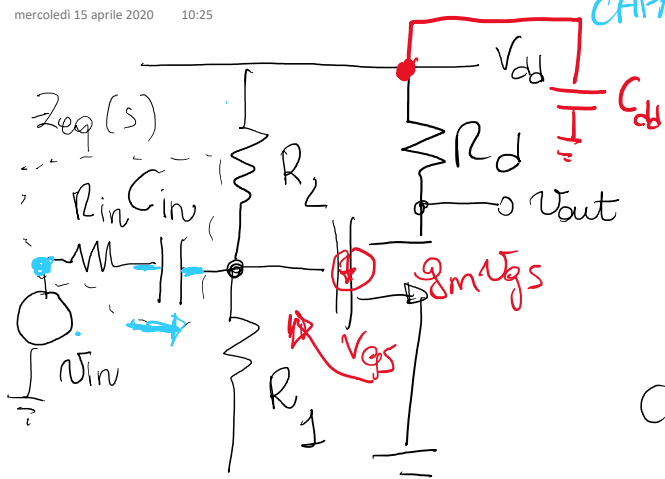


CAPACITA' DI DISACCOUPLAMENTO IN INGRESSO

Stadio polarizzato



$$Z_{eq}(s) = R_{in} + \frac{1}{sC_{in}} = \frac{1 + sC_{in}R_{in}}{sC_{in}}$$

$$C_{in} \rightarrow z(s) = \frac{1}{sC_{in}}$$

$$Z = C_{in} [R_{in} + R_1 || R_2]$$

FUNZIONE DI TRASFERIMENTO (dominio di Laplace)

$$ITF(s) = \frac{\Delta V_{out}(s)}{V_{in}(s)} = \frac{-sC_{in}R_1 || R_2 \cdot g_m R_d}{1 + sC_{in} [R_{in} + R_1 || R_2]} \quad \begin{matrix} \text{ZERO} \\ \text{POLO} \end{matrix}$$

$$V_g(s) = \frac{R_2 || R_1}{Z_{eq}(s) + R_1 || R_2} \quad V_h(s) = V_{gs}(s)$$

$$\begin{aligned} V_{out}(s) &= -g_m V_{gs}(s) R_d = \\ &= -g_m R_d \frac{R_2 || R_1}{Z_{eq}(s) + R_1 || R_2} V_{in}(s) = \\ &= -g_m R_d \frac{R_1 || R_2}{\frac{1 + sC_{in}R_{in}}{sC_{in}} + R_1 || R_2} V_{in}(s) = \\ &= -g_m R_d \frac{sC_{in}R_1 || R_2}{1 + sC_{in}(R_{in} + R_1 || R_2)} V_{in}(s) \end{aligned}$$

* ZERO DI UNA FUNZIONE DI TRASFERIMENTO
 $\exists \bar{s} \text{ t.c. } \forall V_{in}(\bar{s}) \neq 0 \quad V_{out}(\bar{s}) = 0$

* POLO DI UNA FUNZIONE DI TRASFERIMENTO
 $\exists \bar{s} \text{ t.c. } \forall V_{in}(\bar{s}) \neq \infty \quad V_{out}(\bar{s}) = \infty$

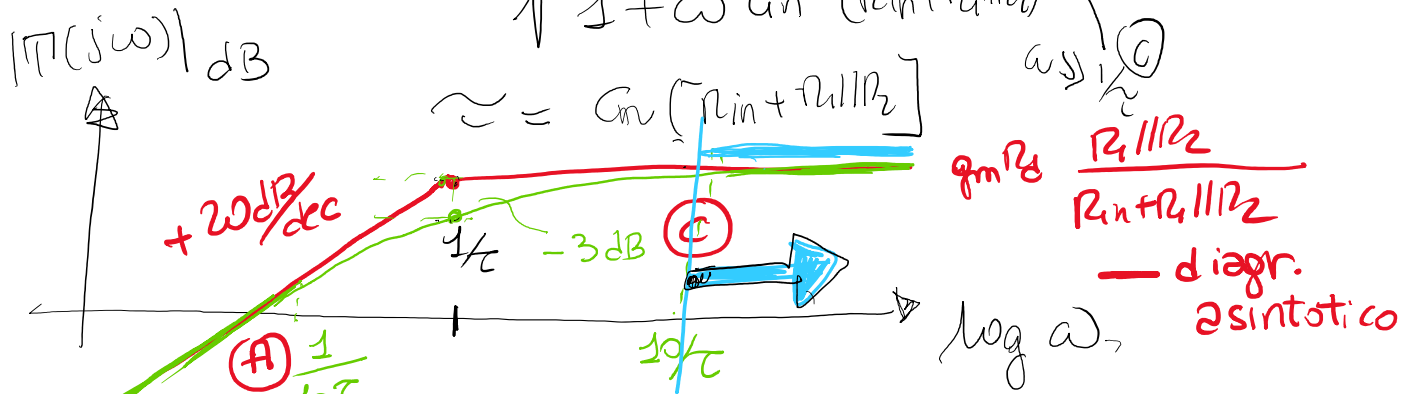
$\exists \bar{s} \text{ t. c. } \forall V_{in}(\bar{s}) \neq \infty \quad V_{out}(s) = \infty$

$S = j\omega$

$T'(j\omega) = -g_m R_d \frac{j\omega C_m R_{in} \parallel R_2}{1 + j\omega C_m (R_{in} + R_1 \parallel R_2)}$

MODULO della FUNZIONE DI TRASFERIMENTO $\omega = 1/c$ (A)

$|T'(j\omega)| = g_m R_d \frac{\omega C_m R_{in} \parallel R_2}{\sqrt{1 + \omega^2 C_m^2 (R_{in} + R_1 \parallel R_2)^2}}$



(A) $\omega \ll 1/c \quad 1 + \omega^2 c^2 \approx 1$

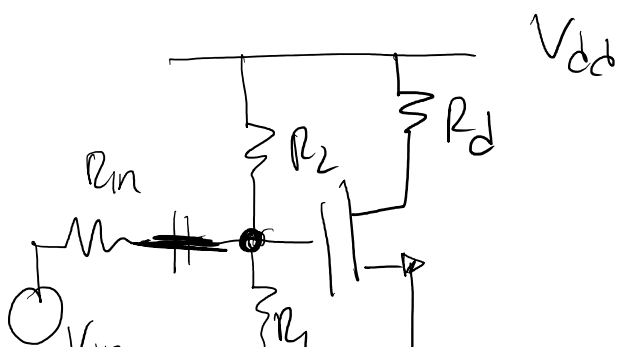
$|T'(j\omega)| \approx g_m R_d \omega C_m R_{in} \parallel R_2$

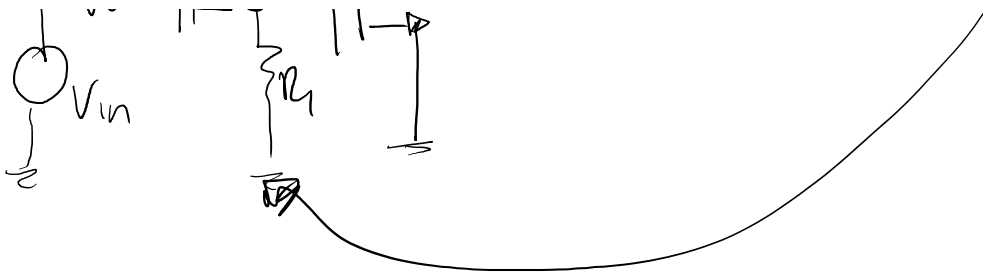
(B) $\omega = 1/c$ POLO

$$|T'(j\omega)| = g_m R_d \frac{1}{\sqrt{2}} \frac{C_m R_{in} \parallel R_2}{R_{in} + R_1 \parallel R_2} = g_m R_d \frac{1}{\sqrt{2}} \frac{C_m R_{in} \parallel R_2}{R_{in} + R_1 \parallel R_2}$$

(C) $\omega \gg 1/c$

$$|T'(j\omega)|_{MF} = g_m R_d \frac{C_m R_{in} \parallel R_2}{\omega C_m (R_{in} + R_1 \parallel R_2)}$$

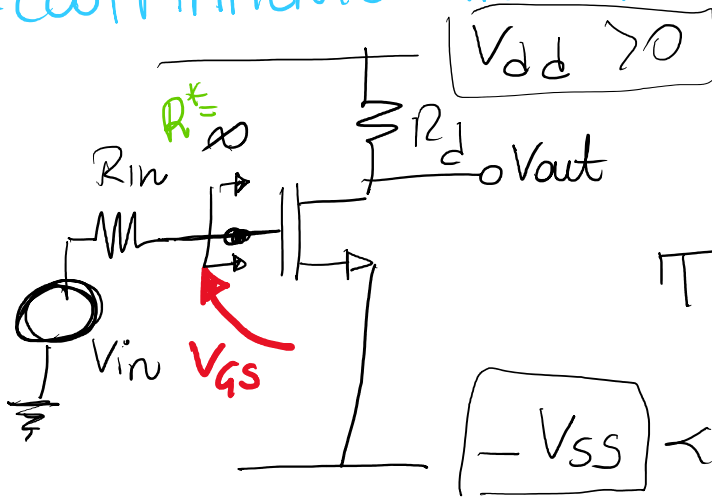




BANDA AUDIO = [20 Hz, 20 kHz]

ACCOPIAMENTO IN CONTINUA

- amplifica anche DC
- ~~nessa~~ resist. ingresso $R_{in} \approx \infty$
- due alimentazioni: una positiva e una negativa



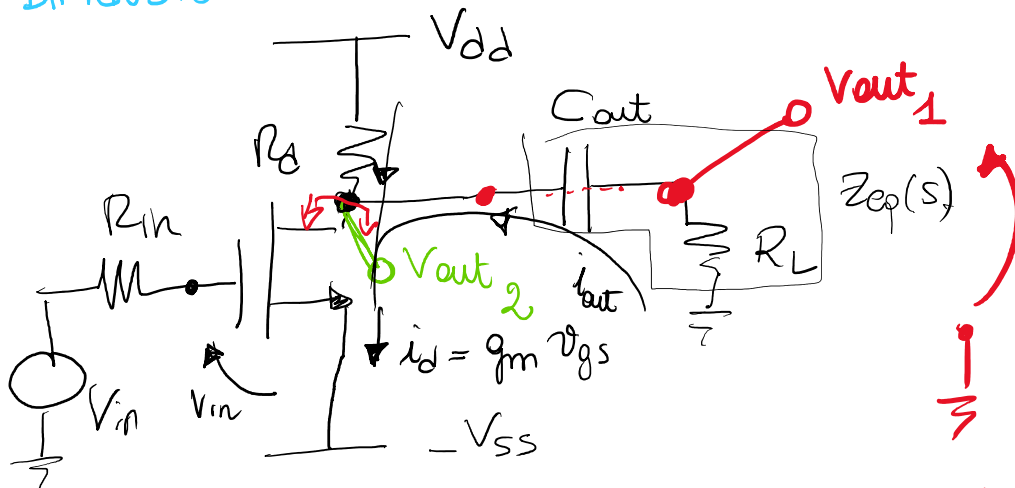
ALIMENTAZIONE DUALE

$$T(s) = -g_m R_d$$

POLARIZZ.

$$V_{GS} = V_G - V_S = 0 - (-V_{SS}) = V_{SS} > 0 \quad (> V_{th})$$

DIMENSIONAMENTO DELLA CAPACITÀ DI DISACCOPIAMENTO DI USU



$$T(s) \triangleq \frac{V_{out1}(s)}{V_{in}(s)} = -g_m$$

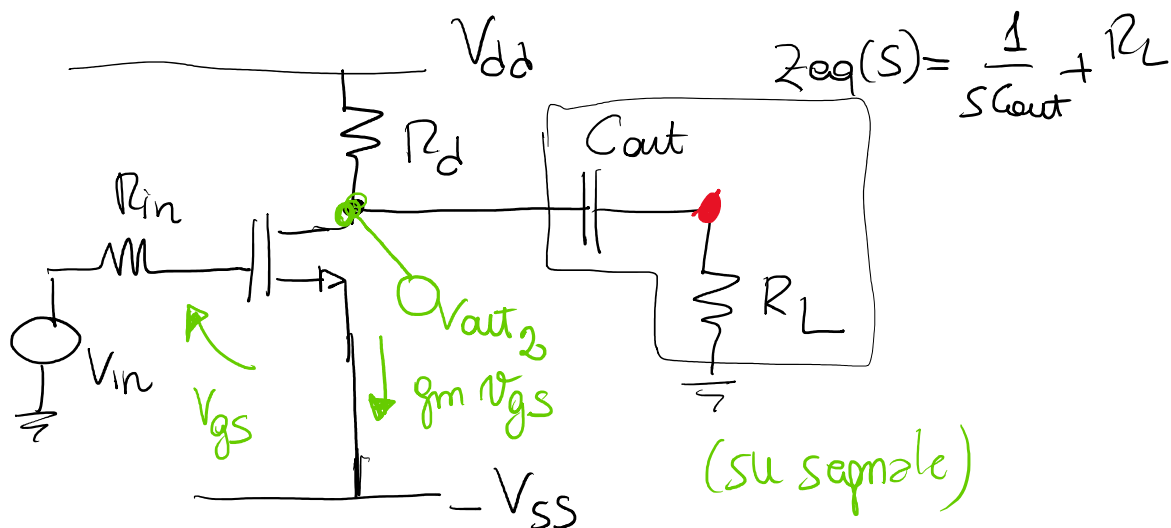
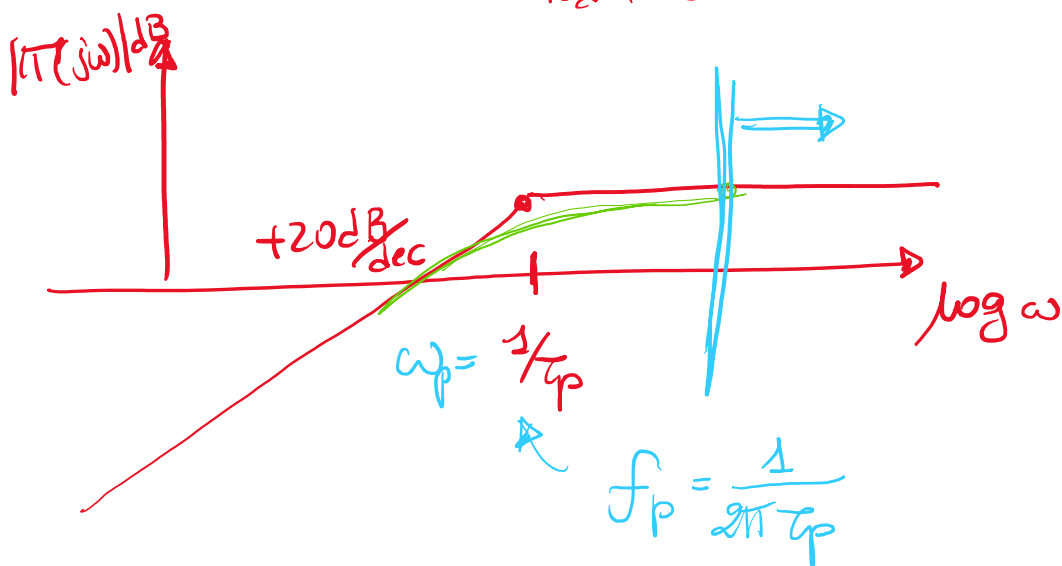
$$\frac{s C_{out} R_d R_L}{1 + s C_{out} (R_d + R_L)}$$

$$i_{out} = g_m v_{gs} \frac{R_d}{R_d + R_L}$$

$$i_{out} = g_m v_{gs} \frac{R_d}{R_d + \underbrace{1/s_{out} + R_L}_{Z_{eq}(s)}}$$

$$V_{out_1} = -i_{out} R_L = -g_m v_{gs} \frac{R_d R_L s_{out}}{1 + s_{out} (R_d + R_L)}$$

- zero nell'origine
- polo $\tau_p = C_{out} (R_d + R_L)$
- $|T(j\omega)|_{HF} = g_m \frac{R_d R_L}{R_d + R_L} = g_m (R_d || R_L)$

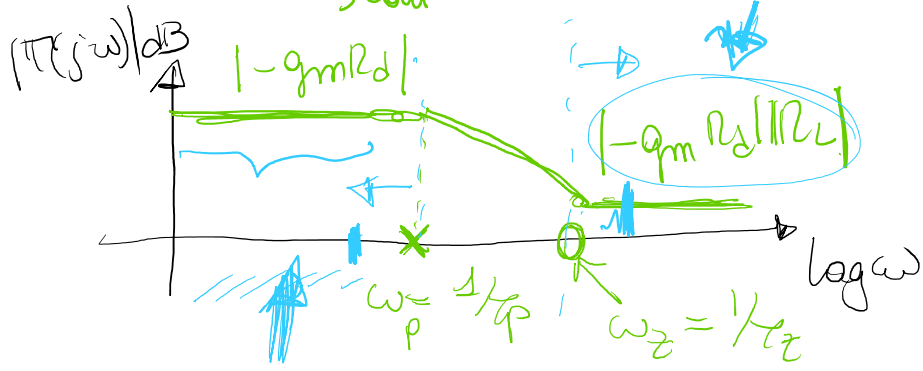


$$V_{out}(s) = -g_m V_{in}(s) R_D \parallel Z_{eq}(s) =$$

$$= -g_m V_{in}(s) \frac{R_D (1 + s C_{out} R_L)}{1 + s C_{out} (R_D + R_L)}$$

ZERO $s_z = -\frac{1}{C_{out} R_L}$
 $\tau_z = C_{out} R_L$
 POLO UGUALE A PRIMA!

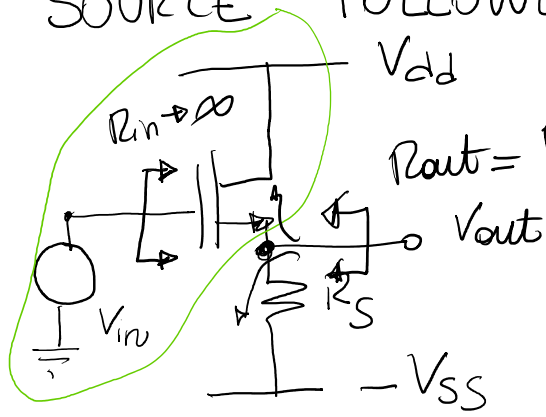
$$\frac{R_D \left(\frac{1}{s C_{out}} + R_L \right)}{R_D + \frac{1}{s C_{out}} + R_L} = \frac{R_D (1 + s C_{out} R_L)}{1 + s C_{out} (R_D + R_L)}$$



$$\tau_p = C_{out} (R_D + R_L)$$

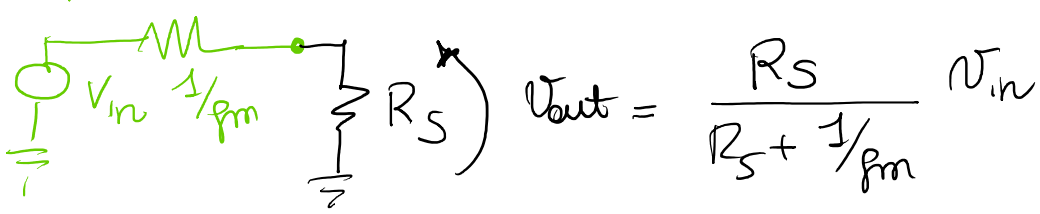
$$\tau_z = C_{out} R_L$$

SOURCE FOLLOWER (inseguitore di source)



$$R_{out} = R_S \parallel \frac{1}{g_m} \approx \frac{1}{g_m}$$

Eq. Thevenin

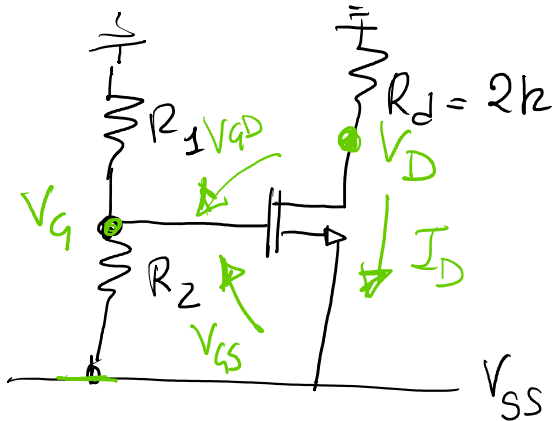


$$G \triangleq \frac{V_{out}}{V_{in}} = \frac{R_S}{R_S + \frac{1}{g_m}} = \frac{g_m R_S}{1 + g_m R_S} < 1$$

- STADIO NON INVERTENTE
- BUFFER DI TENSIONE
 - resist. in ingresso $\rightarrow \infty$
 - resist. di uscita bassa
 - guadagno circa unitario

- BUFFER di un MOSFET
 - resist. univale
 - guadagno circa unitario

ESERCIZIO POLARIZZAZIONE



$$k_m = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} = 1 \text{ mA/V}^2$$

$$V_{Tm} = 0.75 \text{ V}$$

$$R_1 = 825 \text{ k}$$

$$R_2 = 175 \text{ k}$$

$$V_{SS} = -10 \text{ V}$$

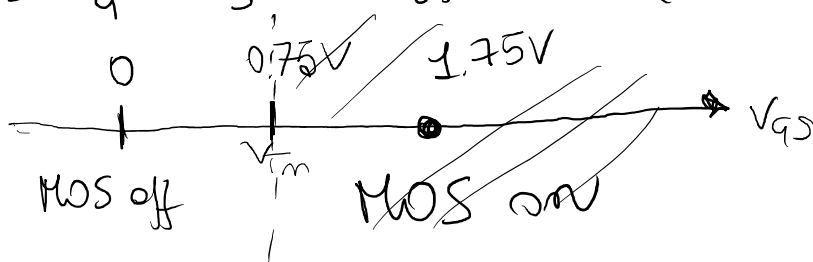
$$I_g = 0 \Rightarrow V_g = V_{SS} + \frac{R_2}{R_1 + R_2} (-10 \text{ V}) =$$

$$= -10 \text{ V} \left[\frac{R_1 + R_2}{R_1 + R_2} + \frac{R_2}{R_1 + R_2} \right] = -10 \text{ V} \frac{R_1}{R_1 + R_2} =$$

$$= -8.25 \text{ V}$$

$$V_{GS} = V_g - V_s = -8.25 \text{ V} - (-10 \text{ V}) = +1.75 \text{ V} > V_{Tm}$$

MOS on



↳ In saturazione nMOS

$$I_D = k_m (V_{GS} - V_{Tm})^2 = 1 \text{ mA/V}^2 (1.75 \text{ V} - 0.75 \text{ V})^2 = 1 \text{ mA}$$

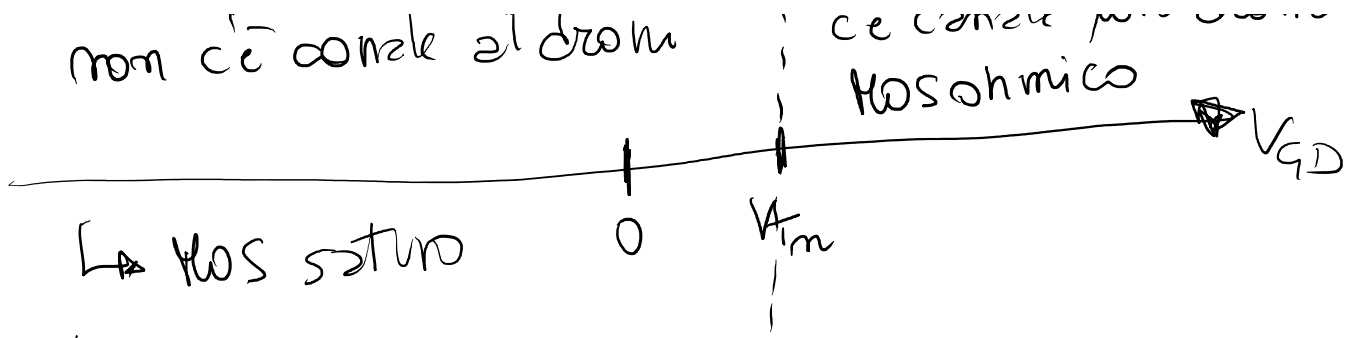
$$V_D = -I_D R_D = -1 \text{ mA} \times 2 \text{ k}\Omega = -2 \text{ V}$$

$$\hookrightarrow V_{GD} = -8.25 \text{ V} - (-2 \text{ V}) = -6.25 \text{ V}$$

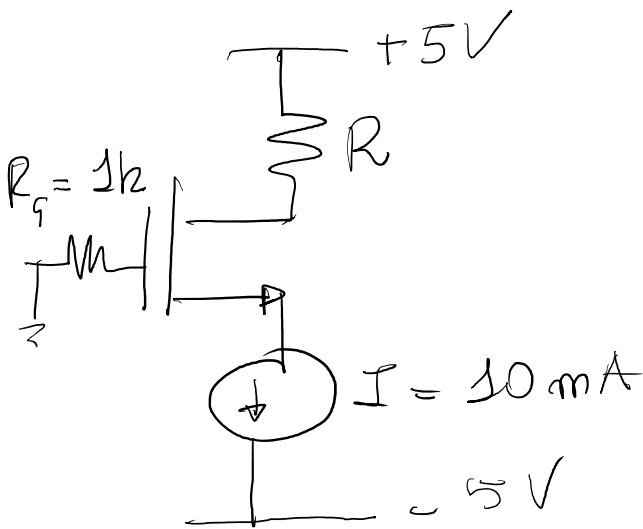
non c'è canale al drain
c'è canale foto drain
MOS ohmico

non c'è canale al drain

ce canale per il MOS ohmico



↓
de MOS saturo



$V_T = 1.5\text{ V}$
Determinare il
massimo valore possibile
per R per mantenere il
MOS saturo?